ACS710

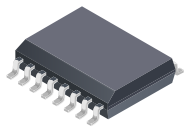
120 kHz Bandwidth, High-Voltage Isolation Current Sensor with Integrated Overcurrent Detection

FEATURES AND BENEFITS

- Industry-leading noise performance with greatly improved bandwidth through proprietary amplifier and filter design techniques
- Small footprint package suitable for space-constrained applications
- 1 mΩ primary conductor resistance for low power loss
- High isolation voltage, suitable for line-powered applications
- User-adjustable Overcurrent Fault level
- Overcurrent Fault signal typically responds to an overcurrent condition in < 2 µs
- Integrated shield virtually eliminates capacitive coupling from current conductor to die due to high dV/dt voltage transients
- Filter pin capacitor improves resolution in low bandwidth applications
- 3 to 5.5 V single supply operation
- Factory-trimmed sensitivity and quiescent output voltage
- Chopper stabilization results in extremely stable quiescent output voltage
- Ratiometric output from supply voltage

CB Certificate Number:
US-23711-A2-UL

PACKAGE: 16-Pin SOIC Hall-Effect IC Package (suffix LA)



Not to scale

DESCRIPTION

The Allegro™ ACS710 current sensor provides economical and precise means for current sensing applications in industrial, commercial, and communications systems. The device is offered in a small footprint surface-mount package that allows easy implementation in customer applications.

The ACS710 consists of a precision linear Hall sensor integrated circuit with a copper conduction path located near the surface of the silicon die. Applied current flows through the copper conduction path, and the analog output voltage from the Hall sensor linearly tracks the magnetic field generated by the applied current. The accuracy of the ACS710 is maximized with this patented packaging configuration because the Hall element is situated in extremely close proximity to the current to be measured.

High-level immunity to current conductor dV/dt and stray electric fields, offered by Allegro proprietary integrated shield technology, results in low ripple on the output and low offset drift in high-side, high-voltage applications.

The voltage on the Overcurrent Input (VOC pin) allows customers to define an overcurrent fault threshold for the device. When the current flowing through the copper conduction path (between the IP+ and IP– pins) exceeds this threshold, the open drain Overcurrent Fault pin will transition to a logic low state. Factory programming of the linear Hall sensor inside of the ACS710 results in exceptional accuracy in both analog and digital output signals.

The internal resistance of the copper path used for current sensing is typically 1 mΩ, for low power loss. Also, the current conduction path is electrically isolated from the low-voltage

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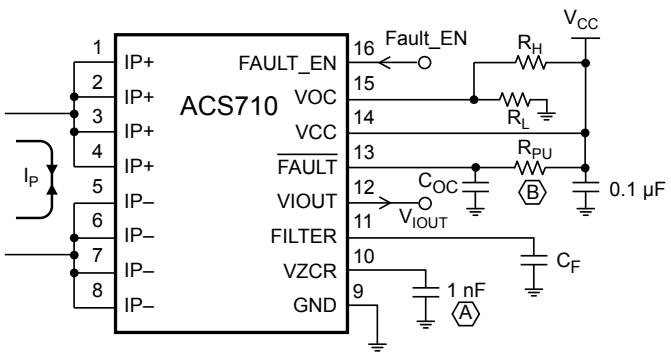
Typical Application Circuit



R_H, R_L	Sets resistor divider reference for V_{OC}
C_F	Noise and bandwidth limiting filter capacitor
C_{OC}	Fault delay setting capacitor, 22 nF maximum
Ⓐ	Use of capacitor required
Ⓑ	Use of resistor optional, 330 kΩ recommended. If used, resistor must be connected between $\overline{\text{FAULT}}$ pin and V_{CC}.

DESCRIPTION (continued)

sensor inputs and outputs. This allows the ACS710 family of sensors to be used in applications requiring electrical isolation, without the use of opto-isolators or other costly isolation techniques.

The ACS710 is provided in a small, surface-mount SOIC16 package. The leadframe is plated with 100% matte tin, which is compatible with standard lead (Pb) free printed circuit board assembly processes. Internally, the device is Pb-free, except for flip-chip high-temperature Pb-based solder balls, currently exempt from RoHS. The device is fully calibrated prior to shipment from the factory.

Applications include:

- Motor control and protection
- Load management and overcurrent detection
- Power conversion and battery monitoring / UPS systems

SELECTION GUIDE

Part Number [1]	Current Sensing Range, I_P (A)	Sens (typ) at V_{CC} = 5 V (mV/A)	Latched Fault	T_A (°C)	Packing
ACS710KLATR-6BB-T	±6	151	Yes	–40 to 125	Tape and Reel, 1000 pieces per reel
ACS710KLATR-10BB-T	±10	85			
ACS710KLATR-12CB-T	±12.5	56			
ACS710KLATR-25CB-T	±25	28			
ACS710KLATR-6BB-NL-T	±6	151	No	–40 to 125	Tape and Reel, 1000 pieces per reel
ACS710KLATR-10BB-NL-T [2]	±10	85			
ACS710KLATR-12CB-NL-T [2]	±12.5	56			
ACS710KLATR-25CB-NL-T	±25	28			

[1] Variant not intended for automotive applications.
[2] Part variants ACS710KLATR-10BB-NL-T and ACS710KLATR-12CB-NL-T are in production but have been determined to be NOT FOR NEW DESIGN. This classification indicates that sale of these devices is currently restricted to existing customer applications. These devices should not be purchased for new design applications because obsolescence in the near future is probable. Samples are no longer available. Date of status change: September 29, 2023.

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ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Notes	Rating	Unit
Supply Voltage	V_{CC}		8	V
Filter Pin	V_{FILTER}		8	V
Analog Output Pin	V_{IOUT}		32	V
Overcurrent Input Pin	V_{OC}		8	V
Overcurrent $\overline{FAULT}$ Pin	$V_{\overline{FAULT}}$		8	V
Fault Enable (FAULT_EN) Pin	$V_{FAULTEN}$		8	V
Voltage Reference Output Pin	V_{ZCR}		8	V
DC Reverse Voltage: VCC, FILTER, VIOUT, VOC, $\overline{FAULT}$, FAULT_EN, and VZCR Pins	V_{Rdcx}		–0.5	V
Excess to Supply Voltage: FILTER, VIOUT, VOC, $\overline{FAULT}$, FAULT_EN, and VZCR Pins	V_{EX}	Voltage by which pin voltage can exceed the VCC pin voltage	0.3	V
Output Current Source	$I_{IOUT(Source)}$		3	mA
Output Current Sink	$I_{IOUT(Sink)}$		1	mA
Operating Ambient Temperature	T_A	Range K	–40 to 125	°C
Junction Temperature	T_J(max)		165	°C
Storage Temperature	T_{stg}		–65 to 170	°C

ISOLATION CHARACTERISTICS

Characteristic	Symbol	Notes	Rating	Unit
Dielectric Surge Strength Test Voltage	V_{SURGE}	Tested ±5 pulses at 2/minute in compliance to IEC 61000-4-5 1.2 µs (rise) / 50 µs (width).	6000	V
Dielectric Strength Test Voltage*	V_{ISO}	Agency type-tested for 60 seconds per IEC/UL 60950-1 (2nd Edition).	3600	V_{RMS}
		Agency type-tested for 60 seconds per UL 1577.	3000	V_{RMS}
Working Voltage for Basic Isolation	V_{WVBI}	Maximum approved working voltage for basic (single) isolation according to IEC/UL 60950-1 (2nd Edition).	870	V_{PK} or VDC
			616	V_{RMS}
Clearance	D_{CL}	Minimum distance through air from IP leads to signal leads.	7.5	mm
Creepage	D_{CR}	Minimum distance along package body from IP leads to signal leads.	7.5	mm

*Production tested for 1 second at 3600 V_{RMS} in accordance with both UL 1577 and IEC/UL 60950-1 (edition 2).

THERMAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions	Value	Unit
Package Thermal Resistance	$R_{\theta JA}$	When mounted on Allegro demo board with 1332 mm^2 (654 mm^2 on component side and 678 mm^2 on opposite side) of 2 oz. copper connected to the primary leadframe and with thermal vias connecting the copper layers. Performance is based on current flowing through the primary leadframe and includes the power consumed by the PCB.	17	°C/W

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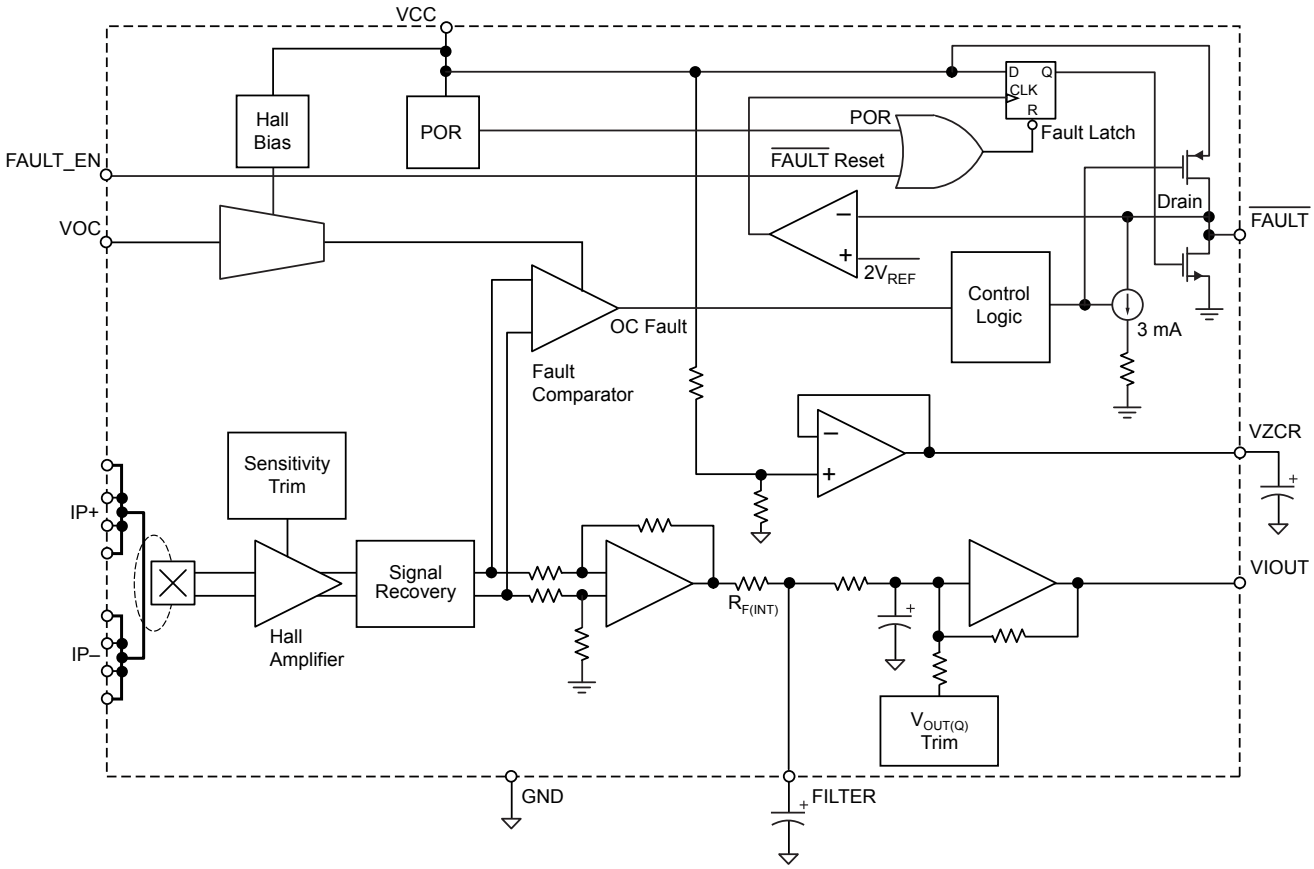
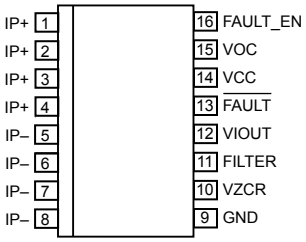
Functional Block Diagram

Latching Version



Pinout Diagram



Terminal List Table, Latching Version

Number	Name	Description
1,2,3,4	IP+	Sensed current copper conduction path pins. Terminals for current being sensed; fused internally, loop to IP– pins; unidirectional or bidirectional current flow.
5,6,7,8	IP–	Sensed current copper conduction path pins. Terminals for current being sensed; fused internally, loop to IP+ pins; unidirectional or bidirectional current flow.
9	GND	Device ground connection.
10	VZCR	Voltage Reference Output pin. Zero current (0 A) reference; output voltage on this pin scales with V_{CC}. (Not a highly accurate reference.)
11	FILTER	Filter pin. Terminal for an external capacitor connected from this pin to GND to set the device bandwidth.
12	VIOUT	Analog Output pin. Output voltage on this pin is proportional to current flowing through the loop between the IP+ pins and IP– pins.
13	$\overline{\text{FAULT}}$	Overcurrent Fault pin. When current flowing between IP+ pins and IP– pins exceeds the overcurrent fault threshold, this pin transitions to a logic low state.
14	VCC	Supply voltage.
15	VOC	Overcurrent Input pin. Analog input voltage on this pin sets the overcurrent fault threshold.
16	FAULT_EN	Enables overcurrent faulting when high. Resets $\overline{\text{FAULT}}$ when low.

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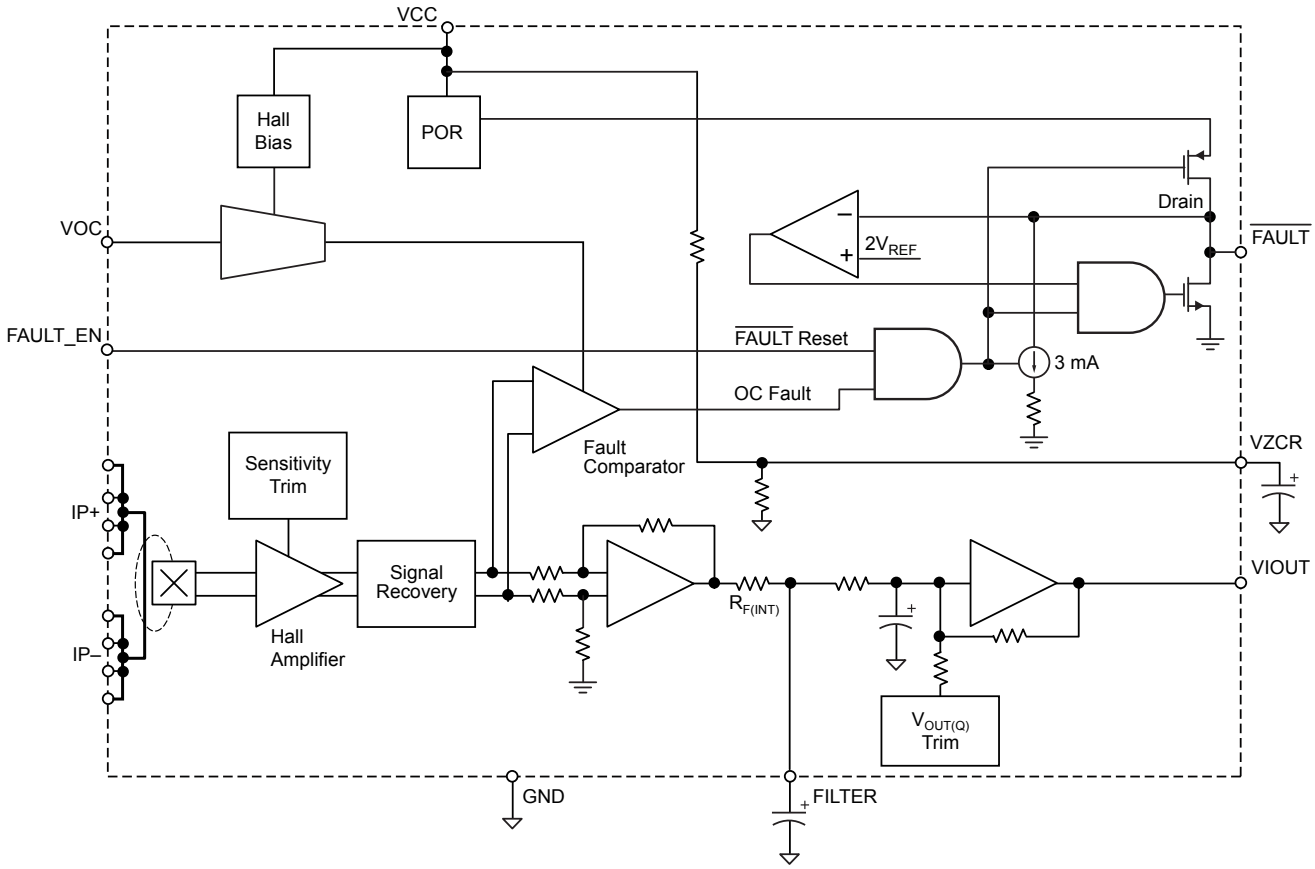
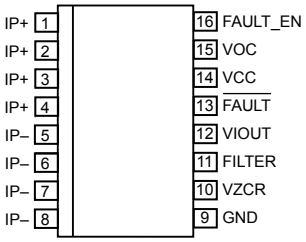
Functional Block Diagram

Non-Latching Version



Pinout Diagram



Terminal List Table, Non-Latching Version

Number	Name	Description
1,2,3,4	IP+	Sensed current copper conduction path pins. Terminals for current being sensed; fused internally, loop to IP– pins; unidirectional or bidirectional current flow.
5,6,7,8	IP–	Sensed current copper conduction path pins. Terminals for current being sensed; fused internally, loop to IP+ pins; unidirectional or bidirectional current flow.
9	GND	Device ground connection.
10	VZCR	Voltage Reference Output pin. Zero current (0 A) reference; output voltage on this pin scales with V_{CC}. (Not a highly accurate reference.)
11	FILTER	Filter pin. Terminal for an external capacitor connected from this pin to GND to set the device bandwidth.
12	VIOUT	Analog Output pin. Output voltage on this pin is proportional to current flowing through the loop between the IP+ pins and IP– pins.
13	$\overline{\text{FAULT}}$	Overcurrent Fault pin. When current flowing between IP+ pins and IP– pins exceeds the overcurrent fault threshold, this pin transitions to a logic low state.
14	VCC	Supply voltage.
15	VOC	Overcurrent Input pin. Analog input voltage on this pin sets the overcurrent fault threshold.
16	FAULT_EN	Enables overcurrent faulting when high.

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COMMON OPERATING CHARACTERISTICS: Valid at T_A = –40°C to 125°C, V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
ELECTRICAL CHARACTERISTICS						
Supply Voltage [1]	V_{CC}		3	–	5.5	V
Nominal Supply Voltage	V_{CCN}		–	5	–	V
Supply Current	I_{CC}	VIOUT open, $\overline{\text{FAULT}}$ pin high	–	11	14.5	mA
Output Capacitance Load	C_{LOAD}	VIOUT pin to GND	–	–	10	nF
Output Resistive Load	R_{LOAD}	VIOUT pin to GND	10	–	–	kΩ
Magnetic Coupling from Device Conductor to Hall Element	MC_{HALL}	Current flowing from IP+ to IP– pins	–	9.5	–	G/A
Internal Filter Resistance [2]	$R_{F(INT)}$		–	1.7	–	kΩ
Primary Conductor Resistance	$R_{PRIMARY}$	T_A = 25°C	–	1	–	mΩ
ANALOG OUTPUT SIGNAL CHARACTERISTICS						
Full Range Linearity [3]	E_{LIN}	$I_P = \pm I_{P0A}$	–0.75	±0.25	0.75	%
Symmetry [4]	E_{SYM}	$I_P = \pm I_{P0A}$	99.1	100	100.9	%
Bidirectional Quiescent Output	$V_{OUT(QBI)}$	I_P = 0 A, T_A = 25°C	–	V_{CC}×0.5	–	V
Noise Density	I_{ND}	Input-referenced noise density; T_A = 25°C, C_L = 4.7 nF	–	400	–	μA /√(Hz)
TIMING PERFORMANCE CHARACTERISTICS						
VIOUT Signal Rise Time	t_r	T_A = 25°C, Swing I_P from 0 A to I_{P0A}, no capacitor on FILTER pin, 100 pF from VIOUT to GND	–	3	–	μs
VIOUT Signal Propagation Time	t_{PROP}	T_A = 25°C, no capacitor on FILTER pin, 100 pF from VIOUT to GND	–	1	–	μs
VIOUT Signal Response Time	$t_{RESPONSE}$	T_A = 25°C, Swing I_P from 0 A to I_{P0A}, no capacitor on FILTER pin, 100 pF from VIOUT to GND	–	4	–	μs
VIOUT Large Signal Bandwidth	f_{3dB}	–3 dB, Apply I_P such that V_{IOUT} = 1 $V_{pk\text{-}pk}$, no capacitor on FILTER pin, 100 pF from VIOUT to GND	–	120	–	kHz
Power-On Time	t_{PO}	Output reaches 90% of steady-state level, no capacitor on FILTER pin, T_A = 25°C	–	35	–	μs
OVERCURRENT CHARACTERISTICS						
Setting Voltage for Overcurrent Switch Point [5]	V_{OC}		V_{CC} × 0.25	–	V_{CC} × 0.4	V
Signal Noise at Overcurrent Comparator Input	I_{NCOMP}		–	±1	–	A
Overcurrent Fault Switch Point Error [6][7]	E_{OC}	Switch point in V_{OC} safe operating area; assumes I_{NCOMP} = 0 A	–	±5	–	%
Overcurrent $\overline{\text{FAULT}}$ Pin Output Voltage	$V_{\overline{\text{FAULT}}}$	1 mA sink current at $\overline{\text{FAULT}}$ pin	–	–	0.4	V
Fault Enable (FAULT_EN Pin) Input Low Voltage Threshold	V_{IL}		–	–	0.1 × V_{CC}	V
Fault Enable (FAULT_EN Pin) Input High Voltage Threshold	V_{IH}		0.8 × V_{CC}	–	–	V
Fault Enable (FAULT_EN Pin) Input Resistance	R_{FEI}		–	1	–	MΩ

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COMMON OPERATING CHARACTERISTICS (continued): Valid at T_A = –40°C to 125°C, V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
OVERCURRENT CHARACTERISTICS (continued)						
Fault Enable (FAULT_EN Pin) Delay [8]	t_{FED}	Set FAULT_EN to low, V_{OC} = 0.25 × V_{CC}, C_{OC} = 0 F; then run a DC I_P exceeding the corresponding overcurrent threshold; then reset FAULT_EN from low to high and measure the delay from the rising edge of FAULT_EN to the falling edge of $\overline{FAULT}$	–	15	–	µs
Fault Enable (FAULT_EN Pin) Delay (Non-Latching versions) [9]	$t_{FED(NL)}$	Set FAULT_EN to low, V_{OC} = 0.25 × V_{CC}, C_{OC} = 0 F; then run a DC I_P exceeding the corresponding overcurrent threshold; then reset FAULT_EN from low to high and measure the delay from the rising edge of FAULT_EN to the falling edge of $\overline{FAULT}$	–	150	–	ns
Overcurrent Fault Response Time	t_{OC}	FAULT_EN set to high for a minimum of 20 µs before the overcurrent event; switch point set at V_{OC} = 0.25 × V_{CC}; delay from I_P exceeding overcurrent fault threshold to $V_{\overline{FAULT}}$ < 0.4 V, without external C_{OC} capacitor	–	1.9	–	µs
Undercurrent Fault Response Time (Non-Latching versions)	t_{UC}	FAULT_EN set to high for a minimum of 20 µs before the undercurrent event; switch point set at V_{OC} = 0.25 × V_{CC}; delay from I_P falling below the overcurrent fault threshold to $V_{\overline{FAULT}}$ > 0.8 × V_{CC}, without external C_{OC} capacitor, R_{PU} = 330 kΩ	–	3	–	µs
Overcurrent Fault Reset Delay	t_{OCR}	Time from $V_{FAULTEN}$ < V_{IL} to $V_{\overline{FAULT}}$ > 0.8 × V_{CC} , R_{PU} = 330 kΩ	–	500	–	ns
Overcurrent Fault Reset Hold Time	t_{OCH}	Time from $V_{FAULTEN}$ <V_{IL} to rising edge of $V_{\overline{FAULT}}$	–	250	–	ns
Overcurrent Input Pin Resistance	R_{OC}	T_A = 25°C, VOC pin to GND	2	–	–	MΩ
VOLTAGE REFERENCE CHARACTERISTICS						
Voltage Reference Output	V_{ZCR}	T_A = 25 °C (Not a highly accurate reference)	0.48 x V_{CC}	0.5 × V_{CC}	0.51 x V_{CC}	V
Voltage Reference Output Load Current	I_{ZCR}	Source current	3	–	–	mA
		Sink current	50	–	–	µA
Voltage Reference Output Drift	ΔV_{ZCR}		–	±10	–	mV

[1] Devices are programmed for maximum accuracy at V_{CC} = 5 V. The device contains ratiometry circuits that accurately alter the 0 A Output Voltage and Sensitivity level of the device in proportion to the applied V_{CC} level. However, as a result of minor nonlinearities in the ratiometry circuit, additional output error will result when V_{CC} varies from the V_{CC} level at which the device was programmed. Customers that plan to operate the device at a V_{CC} level other than the V_{CC} level at which the device was programmed should contact their local Allegro sales representative regarding expected device accuracy levels under these bias conditions.

[2] $R_{F(INT)}$ forms an RC circuit via the FILTER pin.

[3] This parameter can drift by as much as 0.8% over the lifetime of this product.

[4] This parameter can drift by as much as 1% over the lifetime of this product.

[5] See page 8 on how to set overcurrent fault switch point.

[6] Switch point can be lower at the expense of switch point accuracy.

[7] This error specification does not include the effect of noise. See the I_{NCOMP} specification in order to factor in the additional influence of noise on the fault switch point.

[8] Fault Enable Delay is designed to avoid false tripping of an Overcurrent (OC) fault at power-up. A 15 µs (typical) delay will always be needed, every time FAULT_EN is raised from low to high, before the device is ready for responding to any overcurrent event.

[9] During power-up, this delay is 15 µs in order to avoid false tripping of an Overcurrent (OC) fault.

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PERFORMANCE CHARACTERISTICS: T_A Range K, valid at T_A = –40°C to 125°C, V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
***X*6BB CHARACTERISTICS**						
Optimized Accuracy Range [1]	I_{POA}		–7.5	–	7.5	A
Linear Sensing Range	I_R		–14	–	14	A
Noise [2]	$V_{NOISE(rms)}$	T_A = 25°C, Sens = 100 mV/A, C_f = 0, C_{LOAD} = 4.7 nF, R_{LOAD} open	–	4.05	–	mV
Sensitivity [3]	Sens	I_P = 6.5 A, T_A = 25°C	–	151	–	mV/A
		I_P = 6.5 A, T_A = 25°C to 125°C	–	151	–	mV/A
		I_P = 6.5 A, T_A = –40°C to 25°C	–	152	–	mV/A
Electrical Offset Voltage Variation Relative to $V_{OUT(QBI)}$ [4]	V_{OE}	I_P = 0 A, T_A = 25°C	–	±10	–	mV
		I_P = 0 A, T_A = 25°C to 125°C	–	±11	–	mV
		I_P = 0 A, T_A = –40°C to 25°C	–	±40	–	mV
Total Output Error [5]	E_{TOT}	Over full scale of I_{POA}, I_P applied for 5 ms, T_A = 25°C to 125°C	–	±1.6	–	%
		Over full scale of I_{POA}, I_P applied for 5 ms, T_A = –40°C to 25°C	–	±5.6	–	%
***X*10BB CHARACTERISTICS**						
Optimized Accuracy Range [1]	I_{POA}		–10	–	10	A
Linear Sensing Range	I_R		–24	–	24	A
Noise [2]	$V_{NOISE(rms)}$	T_A = 25°C, Sens = 85 mV/A, C_f = 0, C_{LOAD} = 4.7 nF, R_{LOAD} open	–	2.3	–	mV
Sensitivity [3]	Sens	I_P = 10 A, T_A = 25°C	–	85	–	mV/A
		I_P = 10 A, T_A = 25°C to 125°C	–	85	–	mV/A
		I_P = 10 A, T_A = –40°C to 25°C	–	85	–	mV/A
Electrical Offset Voltage Variation Relative to $V_{OUT(QBI)}$ [4]	V_{OE}	I_P = 0 A, T_A = 25°C	–	±5	–	mV
		I_P = 0 A, T_A = 25°C to 125°C	–	±12	–	mV
		I_P = 0 A, T_A = –40°C to 25°C	–	±22	–	mV
Total Output Error [5]	E_{TOT}	Over full scale of I_{POA}, I_P applied for 5 ms, T_A = 25°C to 125°C	–	±1.8	–	%
		Over full scale of I_{POA}, I_P applied for 5 ms, T_A = –40°C to 25°C	–	±5	–	%
***X*12CB CHARACTERISTICS**						
Optimized Accuracy Range [1]	I_{POA}		–12.5	–	12.5	A
Linear Sensing Range	I_R		–37.5	–	37.5	A
Noise [2]	$V_{NOISE(rms)}$	T_A = 25°C, Sens = 56 mV/A, C_f = 0, C_{LOAD} = 4.7 nF, R_{LOAD} open	–	1.50	–	mV
Sensitivity [3]	Sens	I_P = 12.5 A, T_A = 25°C	–	56	–	mV/A
		I_P = 12.5 A, T_A = 25°C to 125°C	–	56	–	mV/A
		I_P = 12.5 A, T_A = –40°C to 25°C	–	57	–	mV/A
Electrical Offset Voltage Variation Relative to $V_{OUT(QBI)}$ [4]	V_{OE}	I_P = 0 A, T_A = 25°C	–	±4	–	mV
		I_P = 0 A, T_A = 25°C to 125°C	–	±14	–	mV
		I_P = 0 A, T_A = –40°C to 25°C	–	±23	–	mV
Total Output Error [5]	E_{TOT}	Over full scale of I_{POA}, I_P applied for 5 ms, T_A = 25°C to 125°C	–	±2.2	–	%
		Over full scale of I_{POA}, I_P applied for 5 ms, T_A = –40°C to 25°C	–	±3.9	–	%

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PERFORMANCE CHARACTERISTICS (continued): T_A Range K, valid at T_A = –40°C to 125°C, V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Units
***X*25CB CHARACTERISTICS**						
Optimized Accuracy Range [1]	I_{POA}		–25	–	25	A
Linear Sensing Range	I_R		–75	–	75	A
Noise [2]	$V_{NOISE(rms)}$	T_A = 25°C, Sens = 28 mV/A, C_f = 0, C_{LOAD} = 4.7 nF, R_{LOAD} open	–	1	–	mV
Sensitivity [3]	Sens	I_P = 25 A, T_A = 25°C	–	28	–	mV/A
		I_P = 25 A, T_A = 25°C to 125°C	–	27.9	–	mV/A
		I_P = 25 A, T_A = –40°C to 25°C	–	28.5	–	mV/A
Electrical Offset Voltage Variation Relative to $V_{OUT(QBI)}$ [4]	V_{OE}	I_P = 0 A, T_A = 25°C	–	±3	–	mV
		I_P = 0 A, T_A = 25°C to 125°C	–	±12	–	mV
		I_P = 0 A, T_A = –40°C to 25°C	–	±18	–	mV
Total Output Error [5]	E_{TOT}	Over full scale of I_{POA}, I_P applied for 5 ms, T_A = 25°C to 125°C	–	±2.9	–	%
		Over full scale of I_{POA}, I_P applied for 5 ms, T_A = –40°C to 25°C	–	±5.2	–	%

[1] Although the device is accurate over the entire linear range, the device is programmed for maximum accuracy over the range defined by I_{POA}. The reason for this is that in many applications, such as motor control, the start-up current of the motor is approximately three times higher than the running current.

[2] V_{pk-pk} noise (6 sigma noise) is equal to 6 × $V_{NOISE(rms)}$. Lower noise levels than this can be achieved by using C_f for applications requiring narrower bandwidth. See Characteristic Performance page for graphs of noise versus C_f and bandwidth versus C_f.

[3] This parameter can drift by as much as 2.4% over the lifetime of this product.

[4] This parameter can drift by as much as 13 mV over the lifetime of this product.

[5] This parameter can drift by as much as 2.5% over the lifetime of this product.

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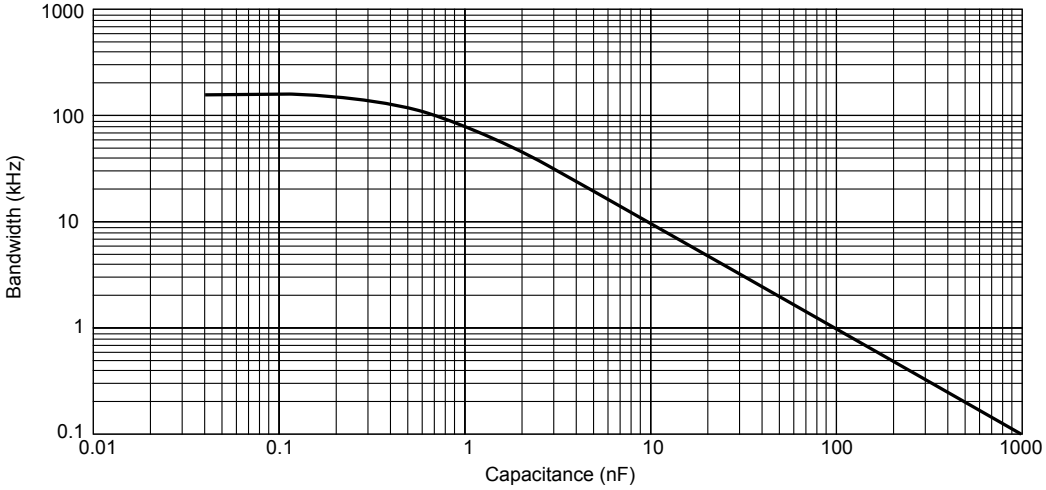
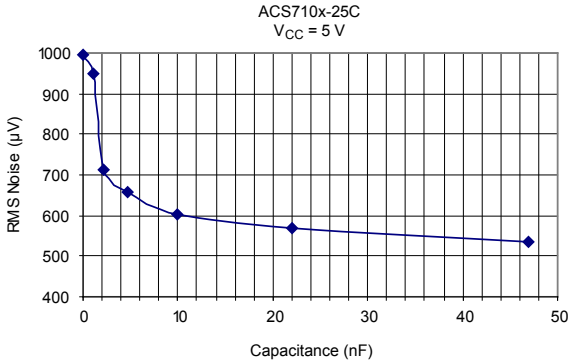
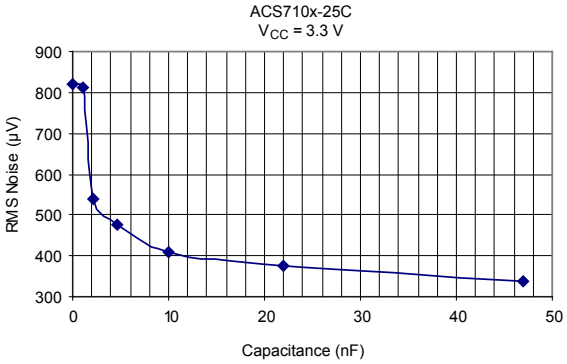
CHARACTERISTIC PERFORMANCE

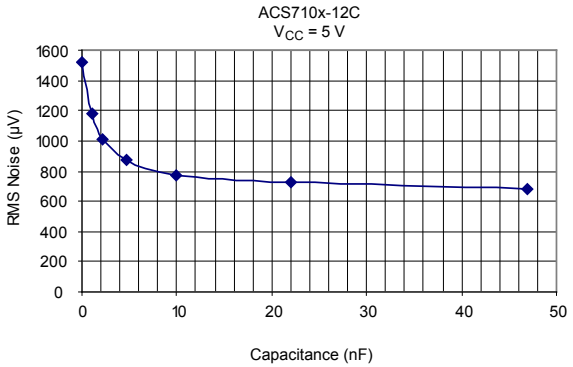
ACS710 Bandwidth versus External Capacitor Value, C_F
Capacitor connected between FILTER pin and GND

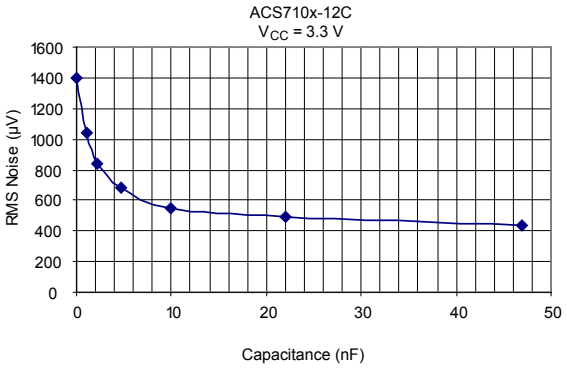


ACS710 Noise versus External Capacitor Value, C_F
Capacitor connected between FILTER pin and GND









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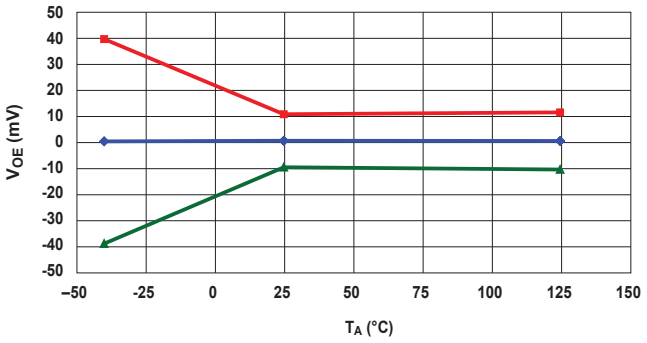
CHARACTERISTIC PERFORMANCE DATA

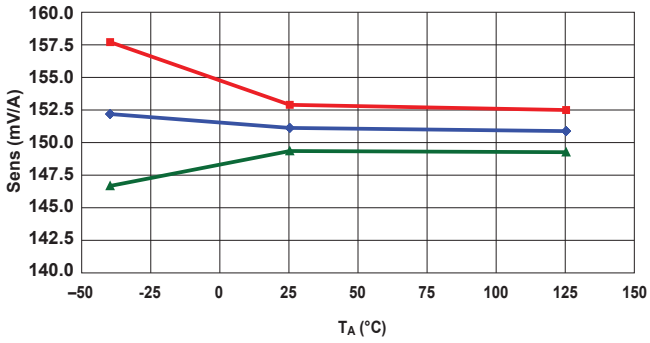
Data taken using the ACS710-6BB

Accuracy Data

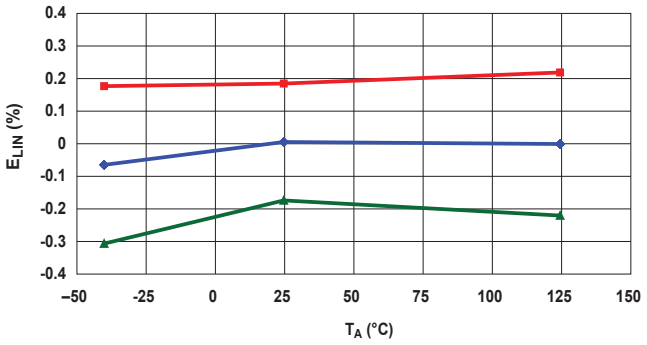
Electrical Offset Voltage versus Ambient Temperature



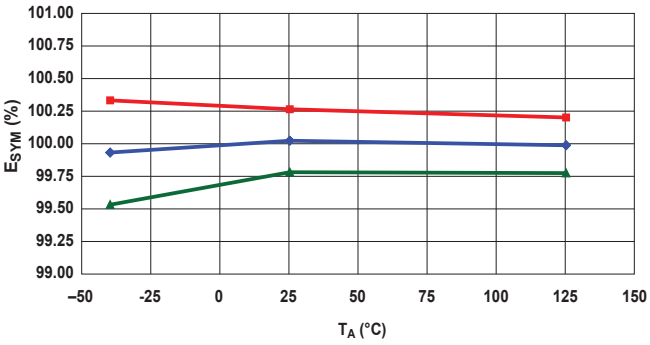
Sensitivity versus Ambient Temperature



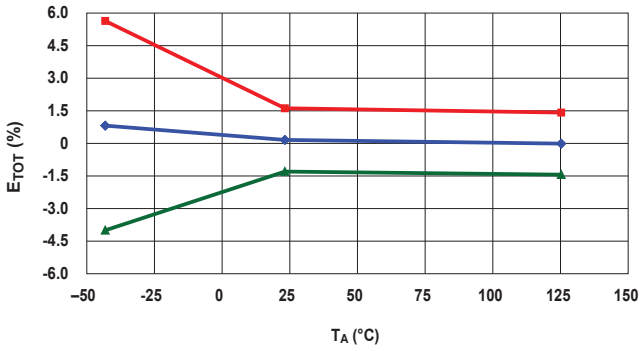
Nonlinearity versus Ambient Temperature

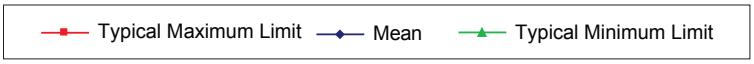


Symmetry versus Ambient Temperature



Total Output Error versus Ambient Temperature





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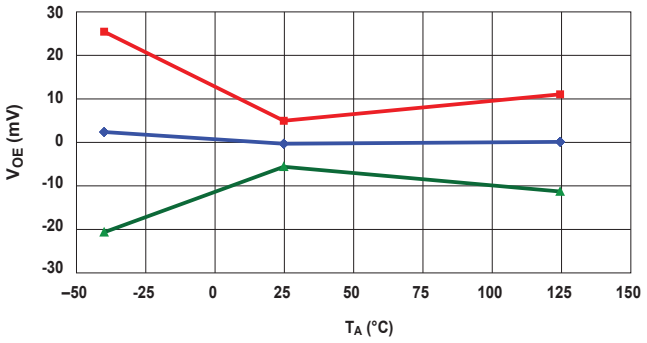
CHARACTERISTIC PERFORMANCE DATA

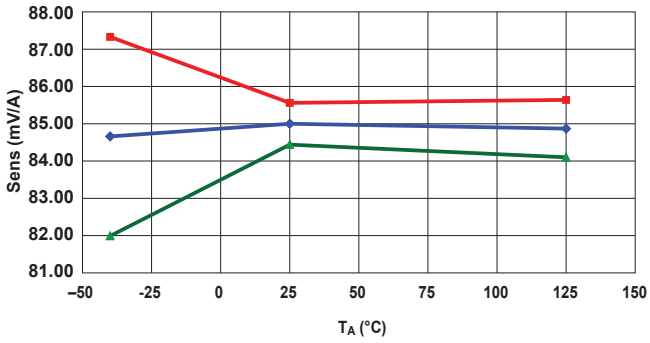
Data taken using the ACS710-10BB

Accuracy Data

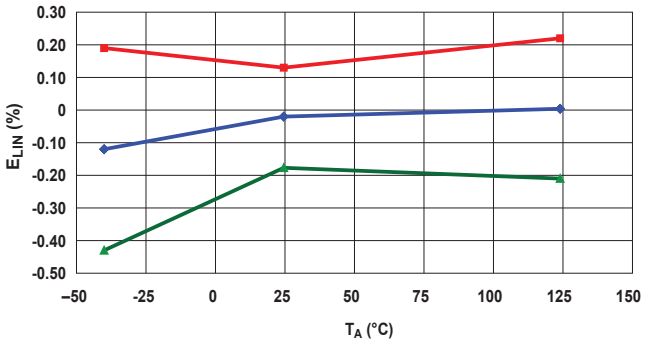
Electrical Offset Voltage versus Ambient Temperature



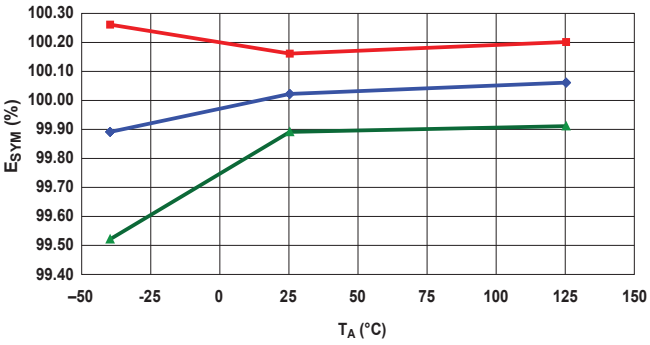
Sensitivity versus Ambient Temperature



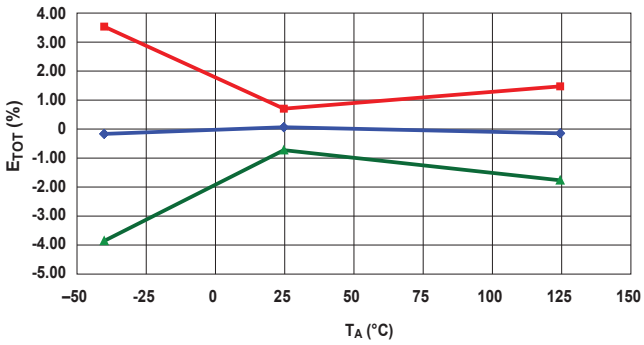
Nonlinearity versus Ambient Temperature

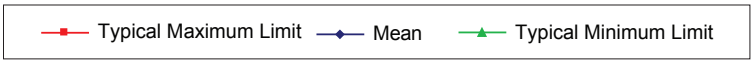


Symmetry versus Ambient Temperature



Total Output Error versus Ambient Temperature





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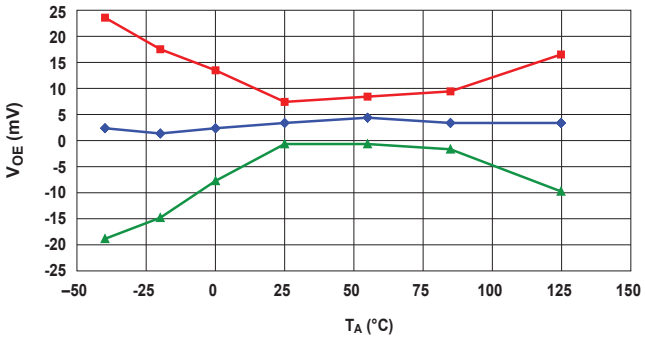
CHARACTERISTIC PERFORMANCE DATA

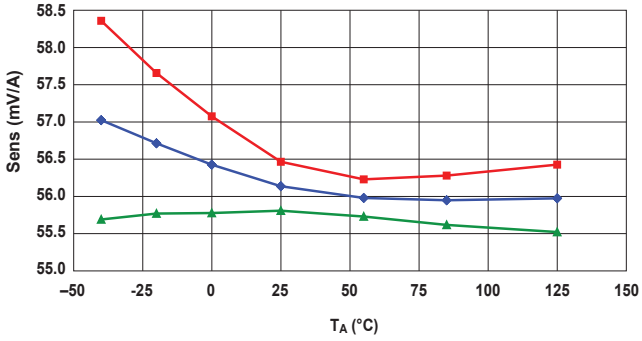
Data taken using the ACS710-12CB

Accuracy Data

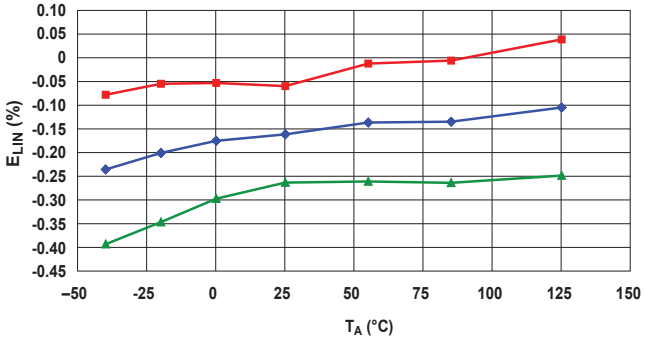
Electrical Offset Voltage versus Ambient Temperature



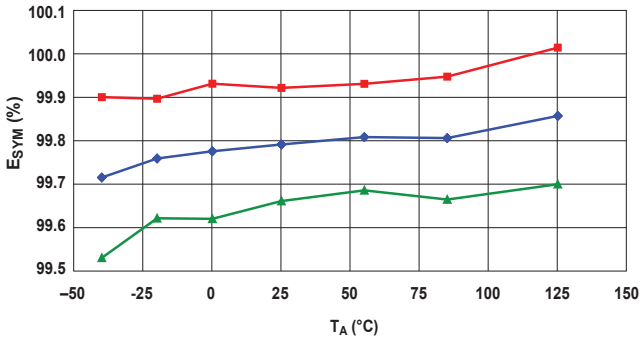
Sensitivity versus Ambient Temperature



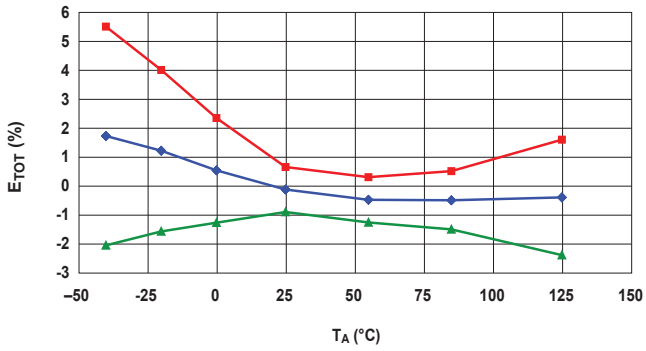
Nonlinearity versus Ambient Temperature

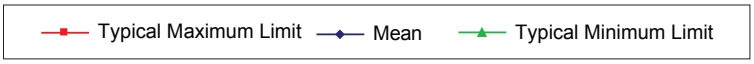


Symmetry versus Ambient Temperature



Total Output Error versus Ambient Temperature





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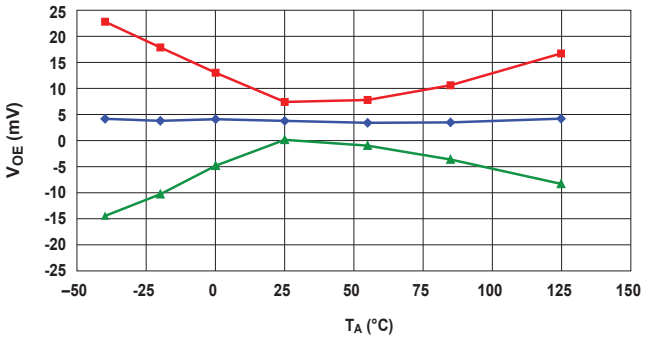
CHARACTERISTIC PERFORMANCE DATA

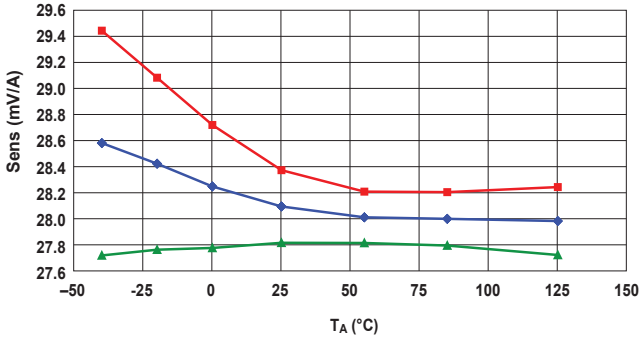
Data taken using the ACS710-25CB

Accuracy Data

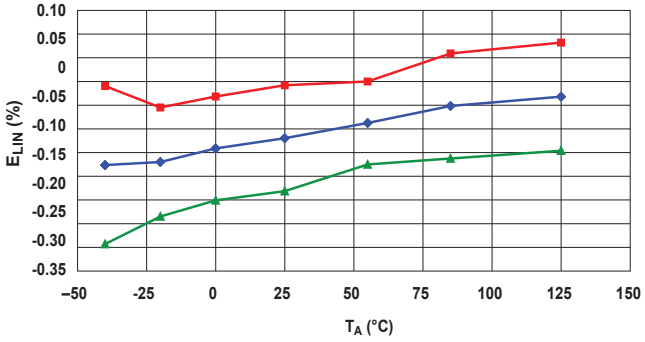
Electrical Offset Voltage versus Ambient Temperature



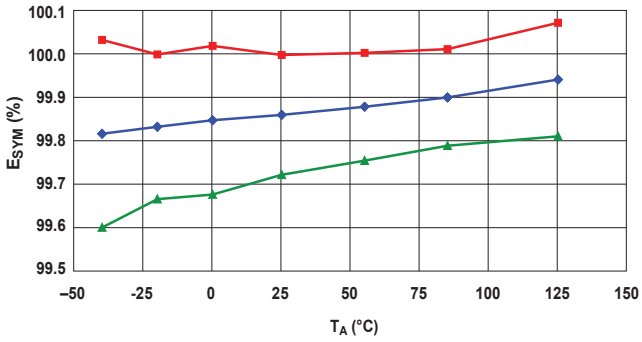
Sensitivity versus Ambient Temperature



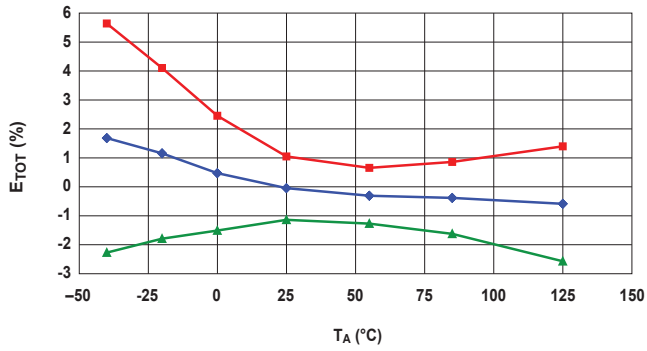
Nonlinearity versus Ambient Temperature

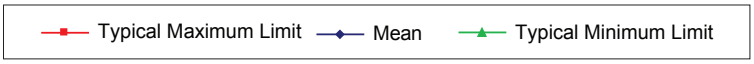


Symmetry versus Ambient Temperature



Total Output Error versus Ambient Temperature





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SETTING OVERCURRENT FAULT SWITCH POINT

Setting 12CB and 25CB Versions

The V_{OC} needed for setting the overcurrent fault switch point can be calculated as follows:

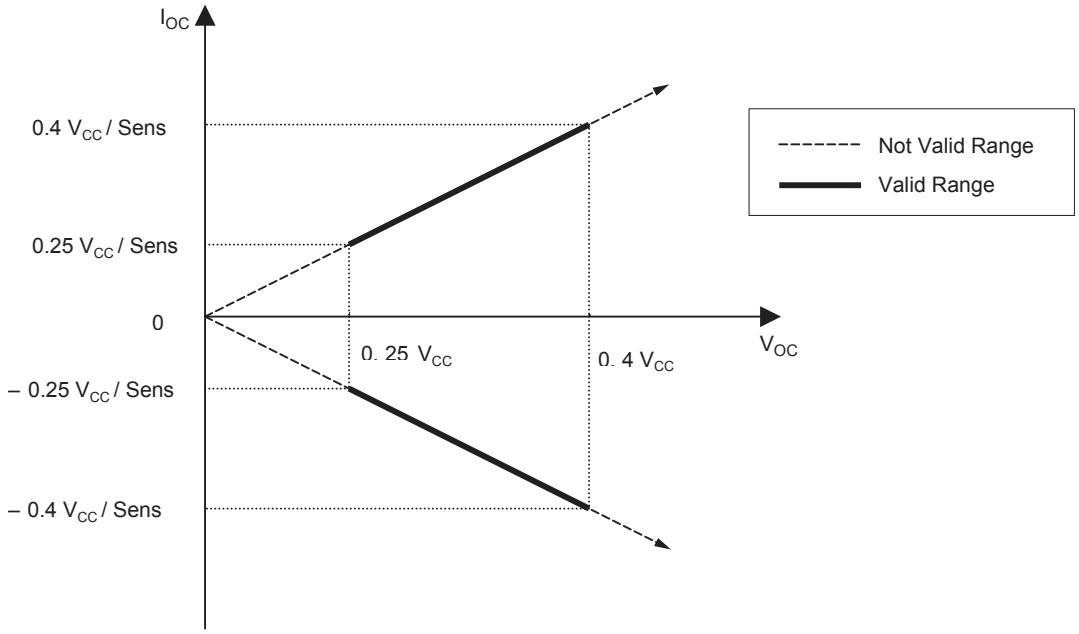
$$V_{OC} = \text{Sens} \times |I_{OC}| \ ,$$

where V_{OC} is in mV, Sens in mV/A, and I_{OC} (overcurrent fault switch point) in A.

|Ioc | is the overcurrent fault switch point for a bidirectional (AC) current, which means a bidirectional sensor will have two symmetrical overcurrent fault switch points, $+I_{OC}$ and $-I_{OC}$.

See the following graph for I_{OC} and V_{OC} ranges.

I_{OC} versus V_{OC}
(12CB and 25CB Versions)



Example: For ACS710KLATR-25CB-T, if required overcurrent fault switch point is 50 A, and V_{CC} = 5 V, then the required V_{OC} can be calculated as follows:

$$V_{OC} = \text{Sens} \times I_{OC} = 28 \times 50 = 1400 \text{ (mV)}$$

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Setting 6BB and 10BB Versions

The V_{OC} needed for setting the overcurrent fault switch point can be calculated as follows:

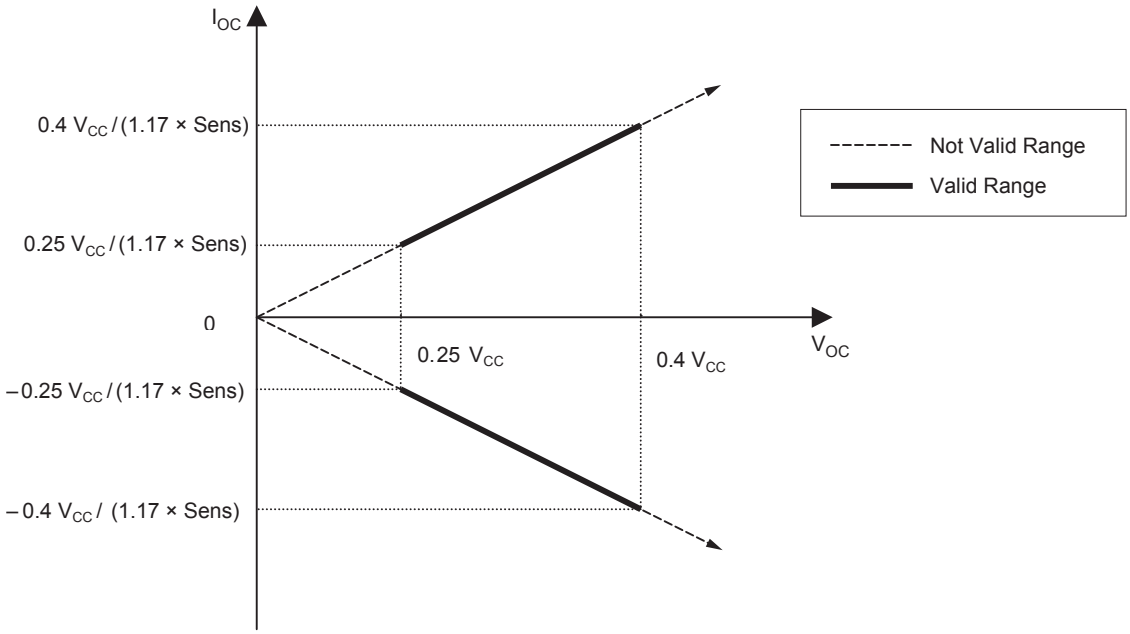
$$V_{OC} = 1.17 \times \text{Sens} \times |I_{OC}| \ ,$$

where V_{OC} is in mV, Sens in mV/A, and I_{OC} (overcurrent fault switch point) in A.

|Ioc | is the overcurrent fault switch point for a bidirectional (AC) current, which means a bidirectional sensor will have two symmetrical overcurrent fault switch points, $+I_{OC}$ and $-I_{OC}$.

See the following graph for I_{OC} and V_{OC} ranges.

I_{OC} versus V_{OC}
(6BB and 10BB Versions)



Example: For ACS710KLATR-6BB-T, if required overcurrent fault switch point is 10 A, and V_{CC} = 5 V, then the required V_{OC} can be calculated as follows:

$$V_{OC} = 1.17 \times \text{Sens} \times I_{OC} = 1.17 \times 151 \times 10 = 1767 \text{ (mV)}$$

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FUNCTIONAL DESCRIPTION (Latching Versions)

Overcurrent Fault Operation

The primary concern with high-speed fault detection is that noise may cause false tripping. Various applications have or need to be able to ignore certain faults that are due to switching noise or other parasitic phenomena, which are application-dependant. The problem with simply trying to filter out this noise in the main signal path is that in high-speed applications, with asymmetric noise, the act of filtering introduces an error into the measurement. To get around this issue, and allow the user to prevent the fault signal from being latched by noise, a circuit was designed to slew the $\overline{\text{FAULT}}$ pin voltage based on the value of the capacitor from that pin to ground. Once the voltage on the pin falls below 2 V, as established by an internal reference, the fault output is latched and pulled to ground quickly with an internal N-channel MOSFET.

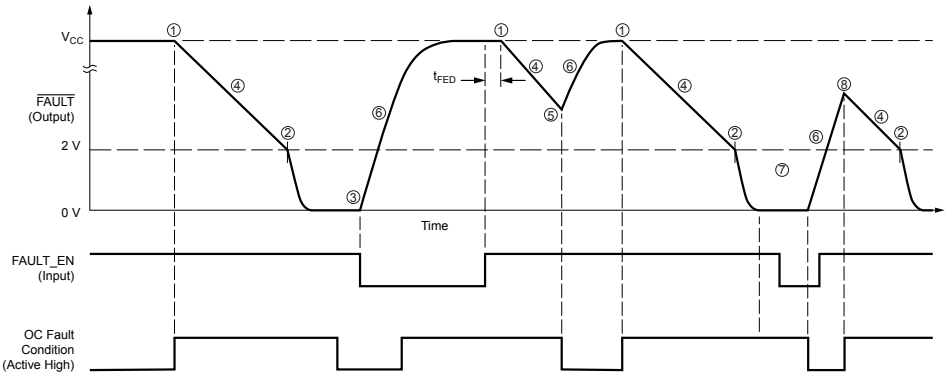
Fault Walkthrough

The following walkthrough references various sections and attributes in the figure below. This figure shows different fault set/reset scenarios and how they relate to the voltages on the $\overline{\text{FAULT}}$ pin, FAULT_EN pin, and the internal Overcurrent (OC) Fault node, which is invisible to the customer.

1. Because the device is enabled (FAULT_EN is high for a minimum period of time, the Fault Enable Delay, t_{FED}, 15 µs typical) and there is an OC fault condition, the device $\overline{\text{FAULT}}$ pin starts discharging.
2. When the $\overline{\text{FAULT}}$ pin voltage reaches approximately 2 V, the fault is latched, and an internal NMOS device pulls the $\overline{\text{FAULT}}$ pin voltage to approximately 0 V. The rate at which the $\overline{\text{FAULT}}$ pin slews downward (see [4] in the figure) is dependent on the external capacitor, C_{OC}, on the $\overline{\text{FAULT}}$ pin.
3. When the FAULT_EN pin is brought low, the $\overline{\text{FAULT}}$ pin starts resetting if no OC fault condition exists, and if FAULT_EN is low for a time period greater than t_{OCH}. The internal NMOS pull-down turns off and an internal PMOS pull-up turns on (see [7] if the OC fault condition still exists).
4. The slope, and thus the delay to latch the fault is controlled by the capacitor, C_{OC}, placed on the $\overline{\text{FAULT}}$ pin to ground. During this portion of the fault (when the $\overline{\text{FAULT}}$ pin is between V_{CC} and 2 V), there is a 3 mA constant current sink, which discharges C_{OC}. The length of the fault delay, t, is equal to:

$$t = \frac{C_{OC} \times (V_{CC} - 2\text{ V})}{3\text{ mA}} \quad (1)$$

   where V_{CC} is the device power supply voltage in volts, t is in seconds and C_{OC} is in Farads. This formula is valid for R_{PU} equal to or greater than 330 kΩ. For lower-value resistors, the current flowing through the R_{PU} resistor during a fault event, I_{PU}, will be larger. Therefore, the current discharging the capacitor would be 3 mA – I_{PU} and equation 1 may not be valid.
5. The $\overline{\text{FAULT}}$ pin did not reach the 2 V latch point before the OC fault condition cleared. Because of this, the fixed 3 mA current sink turns off, and the internal PMOS pull-up turns on to recharge C_{OC} through the $\overline{\text{FAULT}}$ pin.
6. This curve shows V_{CC} charging external capacitor C_{OC} through the internal PMOS pull-up. The slope is determined by C_{OC}.
7. When the FAULT_EN pin is brought low, if the fault condition still exists, the latched $\overline{\text{FAULT}}$ pin will be pulled low by the internal 3mA current source. When fault condition is removed then the Fault pin charges as shown in step 6.
8. At this point there is a fault condition, and the part is enabled before the $\overline{\text{FAULT}}$ pin can charge to V_{CC}. This shortens the user-set delay, so the fault is latched earlier. The new delay time can be calculated by equation 1, after substituting the voltage seen on the $\overline{\text{FAULT}}$ pin for V_{CC}.



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FUNCTIONAL DESCRIPTION (Non-Latching Versions)

Overcurrent Fault Operation

The primary concern with high-speed fault detection is that noise may cause false tripping. Various applications have or need to be able to ignore certain faults that are due to switching noise or other parasitic phenomena, which are application-dependant. The problem with simply trying to filter out this noise in the main signal path is that in high-speed applications, with asymmetric noise, the act of filtering introduces an error into the measurement.
To get around this issue, and allow the user to prevent the fault signal from going low due to noise, a circuit was designed to slew the $\overline{\text{FAULT}}$ pin voltage based on the value of the capacitor from that pin to ground. Once the voltage on the pin falls below 2 V, as established by an internal reference, the fault output is pulled to ground quickly with an internal N-channel MOSFET.

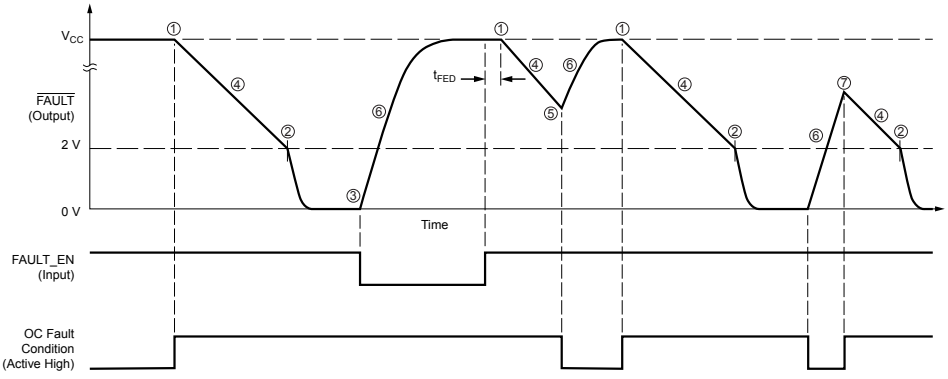
Fault Walkthrough

The following walkthrough references various sections and attributes in the figure below. This figure shows different fault set/reset scenarios and how they relate to the voltages on the $\overline{\text{FAULT}}$ pin, FAULT_EN pin, and the internal Overcurrent (OC) Fault node, which is invisible to the customer.

1. Because the device is enabled (FAULT_EN is high for a minimum period of time, the Fault Enable Delay, t_{FED}, and there is an OC fault condition, the device $\overline{\text{FAULT}}$ pin starts discharging.
2. When the $\overline{\text{FAULT}}$ pin voltage reaches approximately 2 V, an internal NMOS device pulls the $\overline{\text{FAULT}}$ pin voltage to approximately 0 V. The rate at which the $\overline{\text{FAULT}}$ pin slews downward (see [4] in the figure) is dependent on the external capacitor, C_{OC}, on the $\overline{\text{FAULT}}$ pin.
3. When the FAULT_EN pin is brought low, the $\overline{\text{FAULT}}$ pin starts resetting if FAULT_EN is low for a time period greater than t_{OCH}. The internal NMOS pull-down turns off and an internal PMOS pull-up turns on.
4. The slope, and thus the delay to pull the fault low is controlled by the capacitor, C_{OC}, placed on the $\overline{\text{FAULT}}$ pin to ground. During this portion of the fault (when the $\overline{\text{FAULT}}$ pin is between V_{CC} and 2 V), there is a 3 mA constant current sink, which discharges C_{OC}. The length of the fault delay, t, is equal to:

$$t = \frac{C_{OC} \times (V_{CC} - 2\text{ V})}{3\text{ mA}} \quad (2)$$

   where V_{CC} is the device power supply voltage in volts, t is in seconds and C_{OC} is in Farads. This formula is valid for R_{PU} equal to or greater than 330 kΩ. For lower-value resistors, the current flowing through the R_{PU} resistor during a fault event, I_{PU}, will be larger. Therefore, the current discharging the capacitor would be 3 mA – I_{PU} and equation 1 may not be valid.
5. The $\overline{\text{FAULT}}$ pin did not reach the 2 V latch point before the OC fault condition cleared. Because of this, the fixed 3 mA current sink turns off, and the internal PMOS pull-up turns on to recharge C_{OC} through the $\overline{\text{FAULT}}$ pin.
6. This curve shows V_{CC} charging external capacitor C_{OC} through the internal PMOS pull-up. The slope is determined by C_{OC}.
7. At this point there is a fault condition, and the part is enabled before the $\overline{\text{FAULT}}$ pin can charge to V_{CC}. This shortens the user-set delay, so the fault gets pulled low earlier. The new delay time can be calculated by equation 1, after substituting the voltage seen on the $\overline{\text{FAULT}}$ pin for V_{CC}.



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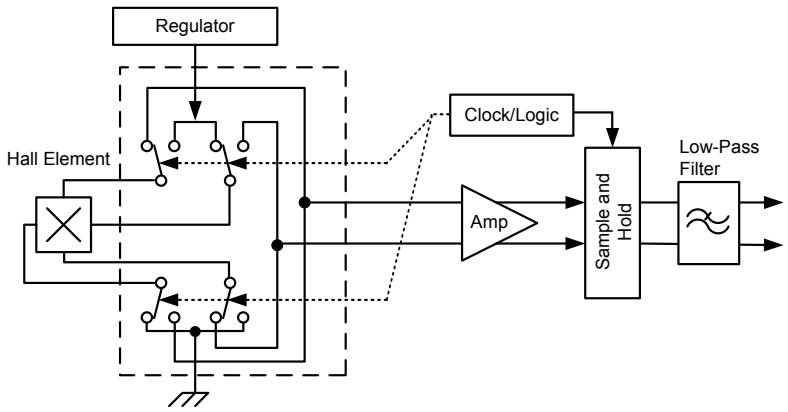
Chopper Stabilization Technique

Chopper stabilization is an innovative circuit technique that is used to minimize the offset voltage of a Hall element and an associated on-chip amplifier. This chopper stabilization technique nearly eliminates Hall IC output drift induced by temperature or package stress effects. This offset reduction technique is based on a signal modulation-demodulation process. Modulation is used to separate the undesired DC offset signal from the magnetically induced signal in the frequency domain. Then, using a low-pass filter, the modulated DC offset is suppressed while the magnetically induced signal passes through the filter. As a result of this chopper stabilization approach, the output voltage from the Hall IC is desensitized to the effects of temperature and mechanical stress. This technique produces devices that have an extremely stable electrical offset voltage, are immune to thermal stress, and have precise recoverability after temperature cycling.

This technique is made possible through the use of a BiCMOS process that allows the use of low-offset and low-noise amplifiers in combination with high-density logic integration and sample-and-hold circuits.



Concept of Chopper Stabilization Technique

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DEFINITIONS OF ACCURACY CHARACTERISTICS

Sensitivity (Sens). The change in sensor output in response to a 1 A change through the primary conductor. The sensitivity is the product of the magnetic circuit sensitivity (G/A) and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

Noise (V_{NOISE}). The product of the linear IC amplifier gain (mV/G) and the noise floor for the Allegro Hall-effect linear IC. The noise floor is derived from the thermal and shot noise observed in Hall elements. Dividing the noise (mV) by the sensitivity (mV/A) provides the smallest current that the device is able to resolve.

Linearity (E_{LIN}). The degree to which the voltage output from the sensor varies in direct proportion to the primary current through its full-scale amplitude. Nonlinearity in the output can be attributed to the saturation of the flux concentrator approaching the full-scale current. The following equation is used to derive the linearity:

$$100\left\{1-\left[\frac{V_{\text{IOUT\_full-scale amperes}} - V_{\text{IOUT(Q)}}}{2\,(V_{\text{IOUT\_1/2 full-scale amperes}} - V_{\text{IOUT(Q)}})}\right]\right\}$$

where $V_{\text{IOUT\_full-scale amperes}}$ = the output voltage (V) when the sensed current approximates full-scale $\pm I_P$.

Symmetry (E_{SYM}). The degree to which the absolute voltage output from the sensor varies in proportion to either a positive or negative full-scale primary current. The following formula is used to derive symmetry:

$$100\left(\frac{V_{\text{IOUT\_+ full-scale amperes}} - V_{\text{IOUT(Q)}}}{V_{\text{IOUT(Q)}} - V_{\text{IOUT\_–full-scale amperes}}}\right)$$

Quiescent output voltage ($V_{IOUT(Q)}$). The output of the sensor when the primary current is zero. For a unipolar supply voltage, it nominally remains at 0.5 × V_{CC}. For example, in the case of a bidirectional output device, V_{CC} = 5 V translates into $V_{IOUT(Q)}$ = 2.5 V. Variation in $V_{IOUT(Q)}$ can be attributed to the resolution of the Allegro linear IC quiescent voltage trim and thermal drift.

Electrical offset voltage (V_{OE}). The deviation of the device output from its ideal quiescent voltage due to nonmagnetic causes. To convert this voltage to amperes, divide by the device sensitivity, Sens.

Accuracy (E_{TOT}). The accuracy represents the maximum deviation of the actual output from its ideal value. This is also known as the total output error. The accuracy is illustrated graphically in the output voltage versus current chart at right. Note that error is directly measured during final test at Allegro.

Accuracy is divided into four areas:

- **0 A at 25°C.** Accuracy of sensing zero current flow at 25°C, without the effects of temperature.
- **0 A over Δ temperature.** Accuracy of sensing zero current flow including temperature effects.
- **Full-scale current at 25°C.** Accuracy of sensing the full-scale current at 25°C, without the effects of temperature.
- **Full-scale current over Δ temperature.** Accuracy of sensing full-scale current flow including temperature effects.

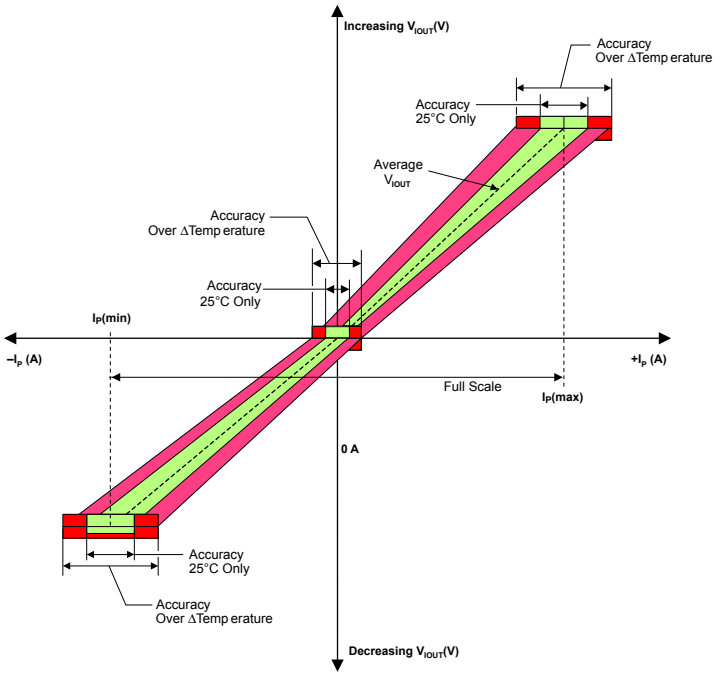
Ratiometry. The ratiometric feature means that its 0 A output, $V_{IOUT(Q)}$, (nominally equal to $V_{CC}/2$) and sensitivity, Sens, are proportional to its supply voltage, V_{CC}. The following formula is used to derive the ratiometric change in 0 A output voltage, $\Delta V_{IOUT(Q)RAT}$ (%).

$$100\left(\frac{V_{\text{IOUT(Q)VCC}} / V_{\text{IOUT(Q)5V}}}{V_{CC} / 5\text{ V}}\right)$$

The ratiometric change in sensitivity, $\Delta Sens_{RAT}$ (%), is defined as:

$$100\left(\frac{Sens_{\text{VCC}} / Sens_{\text{5V}}}{V_{CC} / 5\text{ V}}\right)$$

Output Voltage versus Sensed Current
Accuracy at 0 A and at Full-Scale Current



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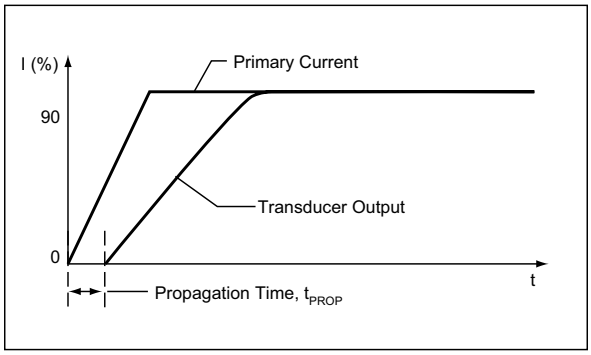
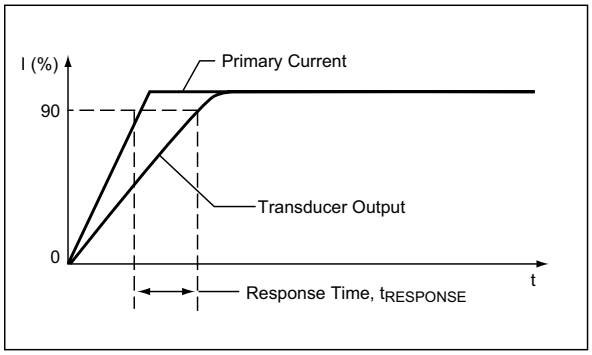
DEFINITIONS OF DYNAMIC RESPONSE CHARACTERISTICS

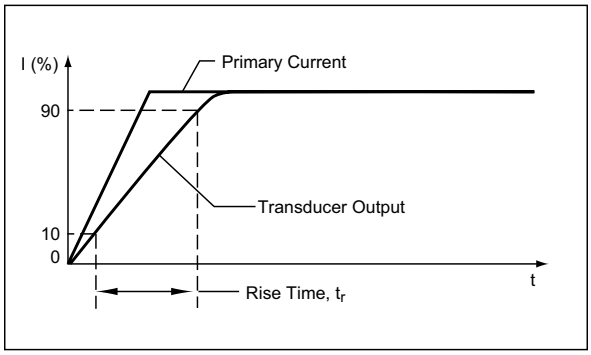
Propagation delay (t_{PROP}). The time required for the sensor output to reflect a change in the primary current signal. Propagation delay is attributed to inductive loading within the linear IC package, as well as in the inductive loop formed by the primary conductor geometry. Propagation delay can be considered as a fixed-time offset and may be compensated.



Response time ($t_{RESPONSE}$). The time interval between a) when the primary current signal reaches 90% of its final value, and b) when the sensor reaches 90% of its output corresponding to the applied current.



Rise time (t_r). The time interval between a) when the sensor reaches 10% of its full-scale value, and b) when it reaches 90% of its full-scale value. The rise time to a step response is used to derive the bandwidth of the current sensor, in which f(–3 dB) = 0.35/t_r. Both t_r and $t_{RESPONSE}$ are detrimentally affected by eddy current losses observed in the conductive IC ground plane.



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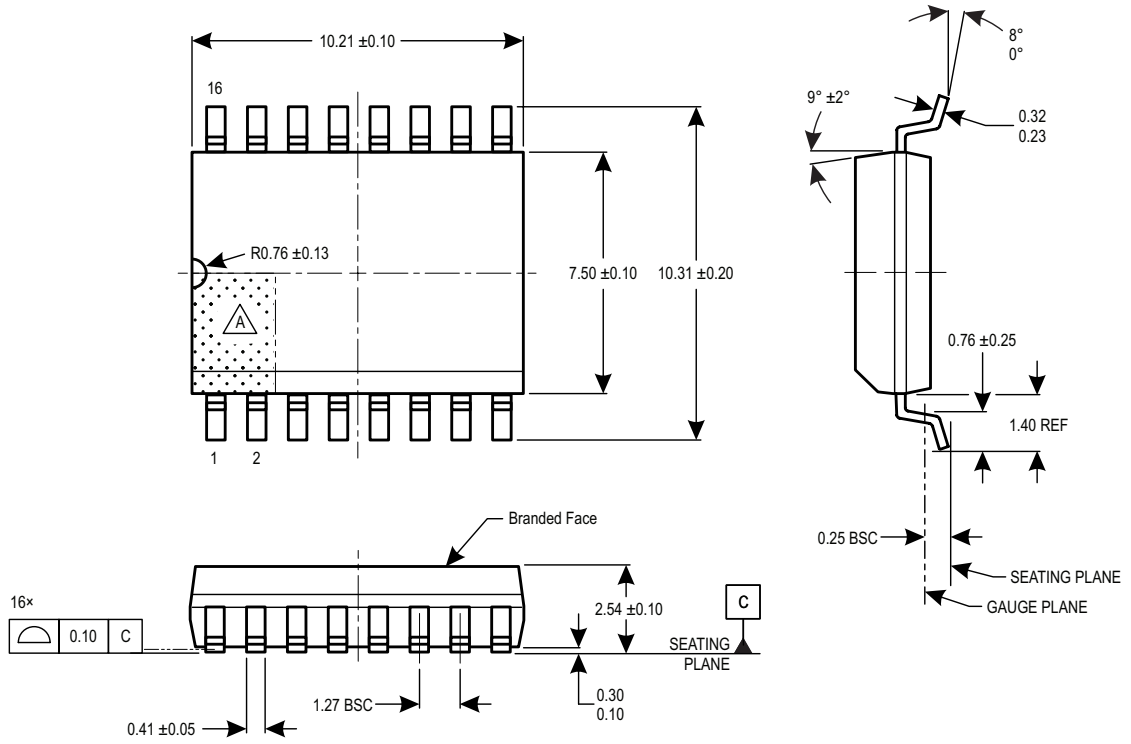
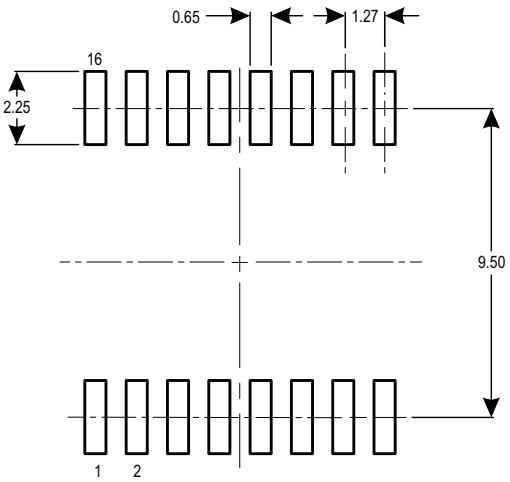
Package LA, 16-Pin SOICW

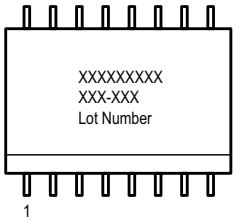
For Reference Only – Not for Tooling Use

(Reference Allegro DWG-0000388, Rev. 1 and JEDEC MS-013AA)
NOT TO SCALE
Dimensions in millimeters
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown





C PCB Layout Reference View



B Standard Branding Reference View

Line 1, 2, 3 = 11 Characters

Line 1: Part Number
Line 2: Temp, Pkg-Amps
Line 3: First 9 characters of Assembly Lot Number

A Terminal #1 mark area

B Branding scale and appearance at supplier discretion

C Reference land pattern layout (reference IPC7351 SOIC127P600X175-8M); all pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances

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REVISION HISTORY

Number	Date	Description
9	June 17, 2013	Add 10BB variant
10	August 19, 2015	Added certificate number under UL stamp on page 1; updated Isolation Characteristics table.
11	June 5, 2017	Updated product status
12	August 31, 2017	Added Dielectric Surge Strength Test Voltage to Isolation Characteristics table (p. 3), and Noise and Noise Density characteristics to Common Operating Characteristics table (p. 6).
13	November 13, 2017	Corrected typo in Dielectric Surge Strength Test Voltage notes of Isolation Characteristics table (p. 3)
14	December 6, 2018	Updated UL certificate number and minor editorial updates
15	February 1, 2019	Updated product status to Pre-End-of-Life
16	January 30, 2020	Updated product status and minor editorial updates
17	February 7, 2022	Updated package drawing (page 22)
18	July 18, 2023	Updated selection guide (page 2); removed extra Noise characteristic entry (page 6)
19	September 29, 2023	Updated part variants ACS710KLATR-10BB-NL-T and ACS710KLATR-12CB-NL-T status to Not for New Design

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